



Ultra-low Stand-by Power HDMI1.4b 3.4Gbps ReDriver DP++ Level-Shifter with 6-step 15dB EQ, DDC Buffer, Channel Swap for Sink Application

Description

PI3HDX511F is a ultra-low power HDMI 1.4b ReDriver and dual-mode DisplayPort level shifter up to 3.4Gbps data rate with 48-bpp Deep Color support.

In the mobile platforms, extending battery hours have been one of the most challenges for system designers. PI3HDX511F has rich power saving features to extend the battery life with 2uA stand-by current and other features like LDO disable pins, Active/Passive DDC switch, Output squelch and HPD (Hot plug Detect) detection.

PI3HDX511F can support both source and sink side system application. For Sink side (Recepticle) application, it supports 6-step input EQ adjustment and data/clock pin order swap.

Features

- → Ultra-low power HDMI 1.4b compliant Redriver
- → Dual-mode DisplayPort Level Shifter/Redriver with pin option
- → Operation up to 3.4 Gbps per lane (340MHz pixel clock)
- → Sink-side application support with TMDS Data & Clock pin swaps and high 15dB EQ options
- → 4K2K Ultra-HD, 3D Video formats (1080p, 1080i, 720p), 48-bit per pixel Deep Color support
- → Ultra-low standby current 2uA with DDC passive switch mode
- → Flexible 6 steps input equalization control steps: 2.5/5/7.5 dB for short cable range and 5/10/15 dB for long cable modes.
- → Pre-emphasis 3 steps setting: 0/1.5/2.5 dB
- → Automatic TMDS output disable with squelch or HPD detection in the no-signal input condition
- → Selectable Active DDC buffer mode for 1.8-3.3V DDC
- → Max 120mW with LDO Bypass 1.5V power supply mode
- → Integrated ESD protection: 8kV HBM for all IO pins per JEDEC standard
- → Power supply: 3.3V single or 3.3/1.5V dual power supply

→ Package: 40-pin TQFN (3x6mm)

Applications

- → Notebook, Desktop computers
- ➔ Displays, Monitors
- → A/V receivers, Set Top Box, Video Players
- → Repeaters and switch boxes



Figure 1-1. DP++ level shifter in Notebook PC

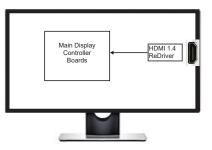


Figure 1-2. HDMI Port in All-In-One PC

Ordering Information

Ordering Number	Package Code	Package Description
PI3HDX511F ZLE(X)	ZL	40-pin TQFN, Lead Free & Green, Tray(Tape & Reels)
PI3HDX511F ZLIE(X)	ZL	Industrial temp support. 40-TQFN, Lead Free & Green

Note: Suffix I = Industrial temp, E = Pb-free and Green, Suffix X = Tape/Reel





2. General Information

2.1 Revision History

Revision	Description of Changes	
June, 2016	P10 - Add Eye opening measurement with different test set-up in the functional description. Expand I-temp grade support in the ordering information.	
July, 2016	Add more contents to assist the system design-in in Application page 20 eg. PCB layout, HDMI compliance report.	
Sep, 2016	Add clarity for the total power dissipation in the Open-drain and the Double termination modes in p1, p12 and p13.	
Feb, 2017	Add Via in the package mechanical drawing	
Jun, 2017	I-temp ordering part number added . Diodes Datasheet style updated.	
Nov, 2017	Package outline drawing updated.	

2.2 Products Comparison

PI3HDX511F		PI3HDX511D	PI3VDP1431	PI3HDX511E
Package	40-pin contact	30-pin contact	32-pin contact	32-pin contact
Body Size(mm)	3x9	2,5x4.5	3x9	3x9
Power Supply	1.5V Core, 3.3V IO power	3.3V	3.3V	3.3V
Data/Clock Pin Swap	Yes	No	No	No
LowPowerLDOBypass	Yes	No	No	No
Power Dissipation	70mA@1.5V, 3mA@3.3V	120mA @ 3.3V	120mA @ 3.3V	120mA @ 3.3V
DDC channels	Passive Switch or Buffers	Passive Switch only	Passive Switch or Buffers	Passive Switch or Buffers
	TMDS ReDriver DP++ Level Shifter	TMDS ReDriver DP++ level shifter	DP++ level shifter	TMDS ReDriver DP++ level shifter
Applications	Sink and Source devices. Power consumption crit- ical Active Cable/Dongle.	Space-limited ultra mo- bile system	Source Devices like NoteBook PC system	Source Devices requires P2P with PI3HDMI511 earlier part.





2.3 Related Products

Part Number	Product Description	
PI3DPX1203B	8.1Gbps Displayport 1.4 Linear Redriver. Low-jitter, Latency Free.	
PI3HDX1204B1	6Gbps HDMI 2.0 Redriver and Displayport Level Shifter, Low-jitter, High EQ.	
PI3HDX414	1:4 Active 3.4Gbps HDMI 1.4b Splitter/DeMux with Signal Conditioning	
PI3HDX412BD	1:2 Active 3.4Gbps HDMI 1.4b Splitter/DeMux with Signal Conditioning	
PI3HDX621	2:1 Active 3.4Gbps HDMI 1.4b Switch	
PI3HDMI336	3:1 Active 2.5Gbps HDMI Switch with I2C control and ARC Transmitter	
PI3DPX1202	5.4Gbps Displayport 1.2 Redriver with built-in auto test mode	
PI3WVR12612	Wide Voltage Range DisplayPort™ & HDMI Video 1:2 Mux/DeMux	

2.4 Reference Documents

Document	Description	
HDMI 1.4	High-Definition Multimedia Interface Specification Version 1.4, HDMI Licensing, LLC	

2.5 Product Status Definition

	Product Status	Definition
Advanced	Formative / In Design	Datasheet contains the design specifications for product development. Specifica- tions may change in any manner without notice.
Preliminary	ninary First Production Datasheet contains preliminary data; supplementary data will be publish date. Diodes Incorporated reserves the right to make product specification at any time without notice to improve design.	
No Identification Needed	Full Production	
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Diodes In- corporated. The datasheet is for reference information only.



PI3HDX511F

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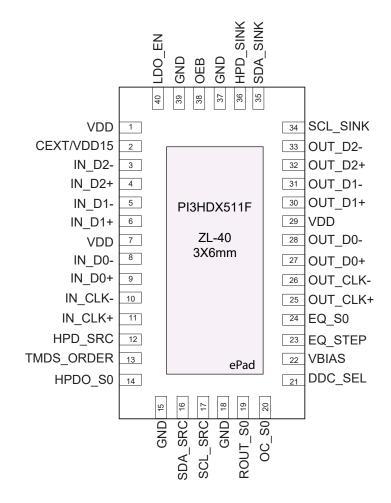
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3. Pin Configuration

3.1 Package Pin-out







3.2 Pin Description

Pin #	Pin Name	Туре	Description	
1	VDD	PWR	3.3V power supply. Add external 0.1uF decoupling capacitor to GND.	
2	CEXT/VDD15	PWR	LDO output for internal core power supplier. VDD15: When LDO_EN is low "0", this shared pin be a VDD15 in dual power supply operation. Apply 1.5V power CEXT: When LDO_EN is high "1", this pin be a CEXT in 3.3V single power supply opera- tion. Add external capacitor (2.2uF-4.7uF) to GND.	
3	IN_D2-	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
4	IN_D2+	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
5	IN_D1-	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
6	IN_D1+	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
7	VDD	PWR	3.3V power supply. Add external 0.1uF decoupling capacitor to GND.	
8	IN_D0-	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
9	IN_D0+	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
10	IN_CLK-	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
11	IN_CLK+	Ι	TMDS inputs. RT=50 Ω and RPD=200 k Ω .	
12	HPD_SRC	0	HPD output to source side	
13	TMDS_ORDER	Ι	TMDS pin order swap control with internal pull high. Default is D2/D1/D0/CLK input sequence.	
14	HPDO_S0	Ι	HPD_SRC output control with internal pull high. Default is Open drain output	
15	GND	GND	Ground	
16	SDA_SRC	IO	Source side DDC Data	
17	SCL_SRC	IO	Source side DDC Clock	
18	GND	GND	Ground	
19	ROUT_S0	Ι	TMDS output enable with double termination or open-drain selection. Default is Active high, double termination output. Active low is open-drain output. Internal pull high to VDD.	
20	OC_S0	Ι	TMDS output pre-emphasis value selection. Default is 1.5dB pre-emphasis setting. Inter- nally tied with 50% of VDD (or VDD/2).	
21	DDC_SEL	Ι	DDC buffer or Passive switch control. Default is Passive switch mode. Internal pull high.	
22	VBIAS	Ι	TMDS input termination voltage control. Default is HDMI input mode. Internally pull high. Pull-down is for Displayport input mode.	
23	EQ_STEP	Ι	EQ_step selection control. Default is low-side setting of 2.5/5/7.5dB. Internally pull high. High-side EQ values are 5/10/15dB with external pull-down.	
24	EQ_S0	Ι	TMDS input three-level equalization selection. Default is middle EQ value setting. Inter- nally 50% of VDD (VDD/2).	
25	OUT_CLK+	0	TMDS outputs with ROUT=50Ω, when ROUT_S0= "1"	
26	OUT_CLK-	0	TMDS outputs with ROUT=50Ω, when ROUT_S0= "1"	
27	OUT_D0+	0	TMDS outputs with ROUT=50Ω, when ROUT_S0= "1"	
28	OUT_D0-	0	TMDS outputs with ROUT=50Ω, when ROUT_S0= "1"	





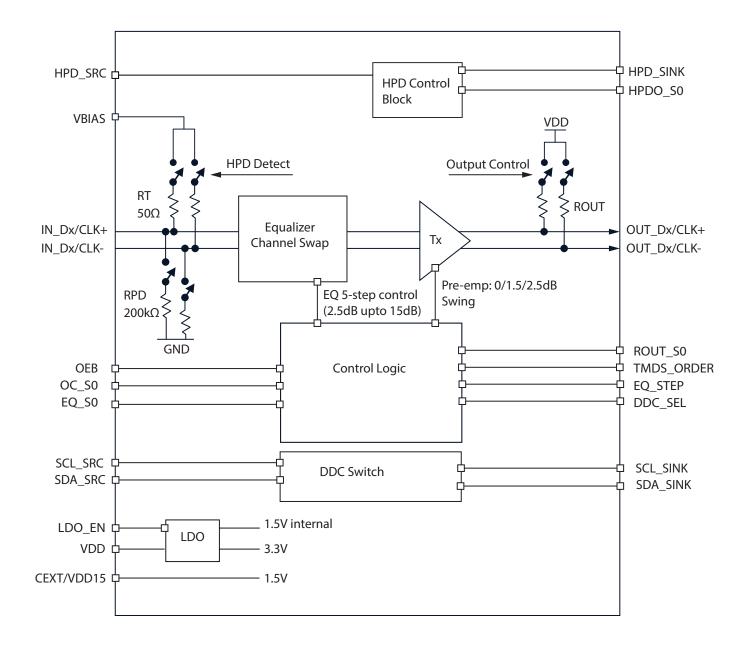
Pin #	Pin Name	Туре	Description	
29	VDD	PWR	3.3V power supply. Add external 0.1uF decoupling capacitor to GND.	
30	OUT_D1+	0	TMDS outputs with ROUT=50 Ω , when ROUT_S0= "1"	
31	OUT_D1-	0	TMDS outputs with ROUT=50 Ω , when ROUT_S0= "1"	
32	OUT_D2+	0	TMDS outputs with ROUT=50 Ω , when ROUT_S0= "1"	
33	OUT_D2-	0	TMDS outputs with ROUT=50 Ω , when ROUT_S0= "1"	
34	SCL_SINK	IO	Sink side DDC Clock for connector	
35	SDA_SINK	IO	Sink side DDC Data for connector	
36	HPD_SINK	Ι	Sink side HPD (Hot Plug Detect) input. Active high pin. Default is inactive for power saving. Internally pull-down at 120 kOhm.	
37	GND	GND	Ground	
38	OEB	Ι	Output Enable control. Active low for normal operation. Active high for disable output HDMI signals. Internally pull-down with 100 k Ω .	
39	GND	GND	Ground	
40	LDO_EN	I	Power supply mode control pin for 1.5/3.3V or 3.3V Default is 3.3V operation with active high. Internally pull high. 1.5/3.3V dual power is active low.	
EPAD	EPAD	GND	Ground	





4. Functional

4.1 IC Block Diagram





PI3HDX511F

4.2 Functional Description

Squelch Mode

Automatic output squelch function disables TMDS output when no Input signal presents. Output Disable (Squelch) Mode uses TMDS Clock signal detection. When low voltage levels on the TMDS input clock are detected, Squelch state enables and TMDS outputs shall be disabled. When the TMDS clock inputs are above the pre-determined threshold voltage, TMDS outputs shall return to the normal swing voltage levels.

TMDS Output Shut Down

When HPD_SINK pin floats or ties to GND, TMDS outputs shall shut down to sleep mode; HPD_SINK does not control DDC channel.TMDS Pin Order Configuration Table

TMDS_ORDER	Functional Description	Note
"0"	CLK/D0/D1/D2 pin order	
"1" or "NC"	D2/D1/D0/CLK pin order	Default

DDC mode selection DDC_SEL Configuration Table

DDC_SEL Functional Description		Note
"0"	Active DDC Buffer	
"1" or "NC"	Passive Switch	Default

LDO Enable Configuration Table

LDO_EN	Pin 1	Pin 2	Functional Description
"0"	3.3V	1.5V	Dual power supply mode 3.3/1.5V
"1"	3.3V	External capacitor	Default. Recommend 2.2~4.7uF pull down capacitor.

Pre-emphasis Truth Table

ROUT_S0	OC_\$0	Single-end Vswing	Pre-emphasis	Functional Description
	"0"	500 mV	0 dB	Open drain output.
"0"	"NC" or VDD/2	500 mV	1.5 dB	Open drain output(Default)
	"1"	500 mV	2.5 dB	Open drain output
	"0"	500 mV	0 dB	Double termination
"1"	"NC" or VDD/2	500 mV	1.5 dB	Double termination(Default)
	"1"	500 mV	2.5 dB	Double termination





TMDS Input Termination Voltage Control VBIAS

VBIAS	Functional Description	
"1", "NC"	HDMI input. VBIAS ties to VDD.	
"0"	DisplayPort input. VBIAS ties to GND.	

EQ Step Selection Control EQ_STEP

EQ_STEP	Functional Description	
"1", "NC"	2.5, 5, 7.5dB EQ setting with EQ_S0 control pin	
"0"	5, 10, 15dB EQ setting with EQ_S0 control pin	

Output Data Signals EQ_S0 Configuration

EQ_S0	Functional Description		Note
	EQ_STEP = "1"	EQ_STEP = "0"	Note
"0"	2.5 dB	5 dB	TMDS Clock(CLK) channel EQ is always fixed as 3dB
"NC" , "VDD/2"	5 dB	10 dB	without pre-emphasis.
"1"	7.5 dB	15 dB	

Sink side Hot Plug Detect HPD_SINK

HPD_SINK	Functional Description
"1"	Normal mode
"0"	Disable output signal for power saving mode

Source side Hot Plug Detect Output Control HPDO_S0

HPDO_S0	Functional Description	
"1" or "NC"	Open drain output (Default)	
"0"	Inverted Buffer output of HPD_SINK signal	

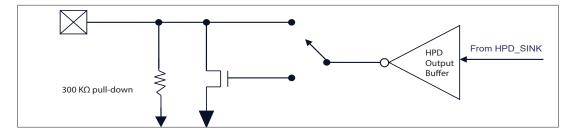
Output Enable Control Truth Table

OEB	Functional Description
"0"	Active Low. Normal mode
"1"	Disable output signal for power saving mode





Source-side Output Block Diagram



Note:

(1) Open drain buffer is recommended with external pull-up resistor to < 4.5V power supply.



5. Electrical Specification

5.1 Absolute Maximum Ratings

Supply Voltage to Ground Potential	-0.5 to +4.5V
All input and Output pins	
5V Tolerance I/O Pins (SDA_SINK, SCL_SINK, HPD_SINK)	
Power Dissipation Continuous	
ESD, HBM	
Storage Temperature	65 °C to +150 °C
Junction temperature T ₁	

Note:

(1) Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to beyond the absolute maximum rating conditions for extended periods may affect inoperability and degradation of device reliability and performance.

5.2 Recommended Operation Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
17	Power Supply Voltage		3.3	3.6	V
V DD			1.5	1.57	
	Ambient Operating Temperature	0		70	°C
1 _A	Industrial Operating Temperature	-40		85	°C

Note

(1) Industrial temperature -40 to +85 °C can be guaranteed by design. Commercial temperature 0 to +70 °C is supported by the production-tested.

5.3 Electrical Characteristics

5.3.1 DC electrical

Power Consumption

Sym- bol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Single p	oower supply					
I _{DD33}	3.3V Power @ 0dB Pre-Emp	Outputs Enable (open drain 500mV, 0 dB pre-empha- sis). terminated OUT_D [0:2] and CLK with 50 ohms to VDD. Exclude 40mA current pass-through from source devices		110		mA
I _{DD33}	3.3V Power@ 0dB Pre-Emp	Outputs Enable (Double termination 500mV, 0 dB pre-emphasis). terminated OUT_D [0:2] and CLK with 50 ohms to VDD. Exclude 40mA current pass-through from source devices		180		mA





Sym- bol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _{DD33}	3.3V Power @ 2.5dB Pre-Emp	Outputs Enable (Open Drain 500mV, 2.5 dB pre-em- phasis). terminated OUT_D [0:2] and CLK with 50 ohms to VDD. Exclude 40mA current pass-through from source devices		133		mA
I _{dd33}	3.3V Power @ 2.5dB Pre-Emp	Outputs Enable (Double termination 500mV, 2.5 dB pre-emphasis). terminated OUT_D [0:2] and CLK with 50 ohms to VDD. Exclude 40mA current pass-through from source devices211			mA	
Dual po	ower supply					
	1.5V @ open drain 500mV, 0 dB	Outputs Enable (open drain 500mV, 0 dB pre-empha- sis), terminated OUT_ D [0:2] and CLK with 50 ohms to Vdd		58	70	mA
$I_{\rm DD15}$	1.5V @ double termi- nation 500mV, 0 dB	Outputs Enable (open drain 500mV, 0 dB pre-empha- sis), terminated OUT_ D [0:2] and CLK with 50 ohms to Vdd		78.2		mA
	1.5V @ double termi- nation 500mV, 2.5 dB	Outputs Enable (open drain 500mV, 0 dB pre-empha- sis), terminated OUT_ D [0:2] and CLK with 50 ohms to Vdd		93.2		mA
I _{DD33}	3.3V IO current			2	3	mA
Stand-b	by current					
	Standby mode Cur- rent; VDD = 3.6V	DDC passive switch (open drain & double termina- tion); OEB = 1, HPD_SINK = 0		40(1)		μΑ
т		DDC active buffer (open drain & double termination); OEB = 1, HPD_SINK = 0,		1.5		mA
I _{stb}		DDC Passive Switch (open drain & double termina- tion); OEB= 1 and HPD_SINK = 0		0		mA
		DDC active buffer (open drain & double termination); OEB= 0 and HPD_SINK = 0		1.44		mA
Squelch	n Current					
т	Squelch mode cur-	DDC passive switch; No input clock VDD=3.6V, HPD_SINK=3.6V		2.68	3.0	mA
I _{sqlh}	rent; VDD = 3.6V	DDC active buffer; No input clock VDD=3.6V, HPD_SINK=3.6V		3.52	4.1	mA

Note:

(1) Current is due to internal 100kΩ pull-down of OE pin drawing extra current (~36uA). If forced by a separate power supply with all other control pins open, lower current is seen (~4uA).





HPD Pins

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit		
HPD_SRC								
V	Buffer Output Low Voltage	IOL = 4 mA			0.4	V		
V _{ol}	Open Drain Output Low Voltage	IOL = 4 mA	0		0.4	V		
V _{OH}	Buffer Output High Voltage	IOH = 0.1 mA	VDD-1.55			V		
I	Off leakage current	VDD=0, VIN=3.6V			25			
I _{oz}	Open drain Output leakage current	VDD=3.6V, VIN=3.6V			25	uA		
HPD_SIN	K							
I	High level digital input current	VIH =5.5V	-10		80	μA		
I	Low level digital input current	VIL = GND	-10		10	μΑ		
V _{IH}	High level digital input voltage	VDD=3.3V	2.0			V		
V _{IL}	Low level digital input voltage		0		0.8	V		

Control pins

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
OEB with 1	00k pull to GND					
I _{IH}	High level digital input current	VIH = 3.3V, VDD=3.3V	-10		80	μA
I _{IL}	Low level digital input current	VIL = GND	-10		10	μΑ
V _{IH}	High level digital input voltage		2.0			V
V _{IL}	Low level digital input voltage		0		0.8	V
		pull low when TMDS is active				
I _{IH}	High level digital input current	VIH =3.3V, VDD=3.3V	-10		40	μA
I _{IL}	Low level digital input current	VIL = GND, VDD=3.3V	-40		10	μA
ROUT_S0,	TMDS_ORDER, EQ_STEP, VBIA	S, LDO_EN, DDC_SEL, HPD	D_\$0			
I _{IH}	High level digital input current	VIH =VDD	-10		10	μA
I _{IL}	Low level digital input current	VIL = GND	-20		10	μA
V _{IH}	High level digital input voltage		2.0			V
V _{IL}	Low level digital input voltage		0		0.8	V

DDC Channel Switch

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I	Input leakage current	DDC switch is off, $Vin = 5.5V$	-10		30	μA
C _{IO}	Input/Output capacitance when passive switch on	VIpp(peak-peak) = 1V, 100 kHz		10		pF
R _{ON}	Passive Switch resistance	IO = 3mA, $VO = 0.4V$		30	50	Ω
V _{PASS}	Switch Output voltage	VI=3.3V, II=100uA VDD=3.3V	1.5	2.0	2.5	V





DDC Channel Buffers

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{IH_SRC}	Source Side DDC Buffer Input High Voltage		0.6			V
V _{IL_SRC}	Source Side DDC Buffer Input Low Voltage				0.4	V
V _{ol_src}	Source Side DDC Buffer Output Low Voltage	External pull-up to VDD	0.47	0.52	0.6	V
V _{ol_sink}	Sink Side DDC Buffer Output Low Voltage	from $1.5k\Omega$ to $10k\Omega$			0.2	V
VI _{H_SINK}	Sink Side DDC Buffer Input High Voltage		2.0			V
V _{IL_SINK}	Sink Side DDC Buffer Input Low Voltage				0.8	V
C _{I_SRC}	Source side DDC capacitance when active switch is on, or passive switch off	VIpp(peak-peak)=1V, 100		5		pF
C _{I_SINK}	Sink side DDC capacitance when active switch is on, or passive switch off	KHz		5		pF

TMDS Differential Pins

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{OH}	Single-ended high level output voltage		VDD-10		VDD+10	mV
V _{ol}	Single-ended low level output voltage	_	VDD-600		VDD-400	mV
V _{SWING}	Single-ended output swing voltage		400		600	mV
V _{OD(O)} *1	Overshoot of output differential voltage	VDD = 3.3V, ROUT=50 Ω			180*1	mV
V _{OD(U)} ^{*2}	Undershoot of output differential voltage				200*2	mV
V _{OC(SS)}	Change in steady-state common- mode output voltage between logic states				5	mV
T	Short Circuit output current at open drain mode	Short to VDD	-12		12	mA
I _{OS}	Short Circuit output current at double termina- tion mode	Short to VDD	-24		24	mA
V _{I(open)}	Single-ended input voltage under high imped- ance or open case	II = 10uA	VDD-10		VDD +10	mV
R _T	Input termination resistance	VIN = 2.9V	45	50	55	Ω
I _{oz}	Leakage current with Hi-Z I/O	VDD = 3.6V			30	μΑ

(1) Overshoot of output differential voltage VOD(O) = (VSWING(MAX) * 2) * 15%

(2) Undershoot of output differential voltage VOD(O) = (VSWING(MIN) * 2) * 25%



PI3HDX511F

5.3.2 AC Electrical

TMDS differential pins

Symbol	Parameter	Test	Min.	Тур.	Max.	Units
t _{pd}	Propagation delay				2000	
	Differential output signal rise/fall time (20% - 80%), open drain, 0dB pre-em- phasis			120		
t _r /t _f	Differential output signal rise/fall time (20% - 80%), open drain, 2.5dB pre-em- phasis	VDD = 3.3V, ROUT = 50Ω		100		
t _{sk} (p)	Pulse skew	-		10	50	ps
t _{sk} (D)	Intra-pair differential skew			23	50	
t _{sk} (o)	Inter-pair differential skew				100	
t _{jit} (pp)	Peak-to-peak output jitter CLK residual jitter			30	60	
t _{jit} (pp)	Peak-to-peak output jitter DATA resid- ual Jitter	– Data Input = 3.4 Gbps		40	70	
t _{en}	Enable time				50	
t _{dis}	Disable time				0.01	— μs

DDC I/O pins (Passive switch mode)

Symbol	Parameter	Test	Min.	Тур.	Max.	Units
t _{pd(DDC)}	Propagation delay from SCL_SINK/SDA_SINK to SCL/SDA, or SCL/ SDA to SCL_SINK/SDA_SINK in passive switch.	CL = 10pF in passive switch			5	ns

DDC I/O pins (Active buffer mode)

Symbol	Parameter	Test	Min.	Тур.	Max.	Units
t _{PLH}	LOW-to-HIGH propagation delay	SCL/SDA to SCL/SDA_SINK		169	255	ns
t _{PHL}	HIGH-to-LOW propagation delay	SCL/SDA to SCL/SDA_SINK	10	103	300	ns
t _{PLH}	LOW-to-HIGH propagation delay	SCL/SDA_SINK to SCL/SDA	25	67	110	ns
t _{PHL}	HIGH-to-LOW propagation delay	SCL/SDA_SINK to SCL/SDA		118	230	ns

Control and Status pins (HPD_SINK, HPD)

Symbol	Parameter	Test	Min.	Тур.	Max.	Units
t _{pd(HPD)}	Propagation delay from HPD_SINK to the active port of HPD, high to low	$CL = 10 pF$, pull high resistor= $1k\Omega$		10		ns





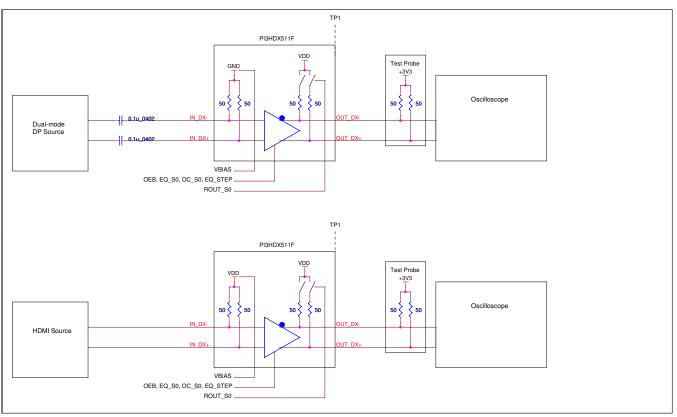


Figure 5-1 Electrical Characteristic Test Circuit

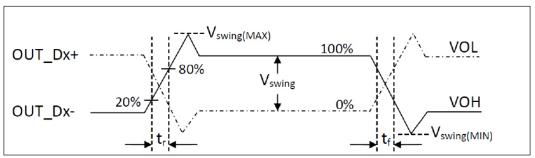


Figure 5-2 Vswing, t_r/t_r Definition

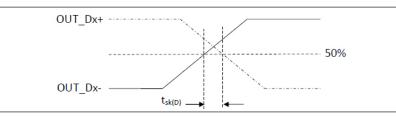


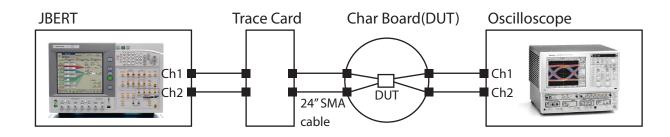
Figure 5-3 Intra-pair Skew($t_{sk(D)}$) Definition



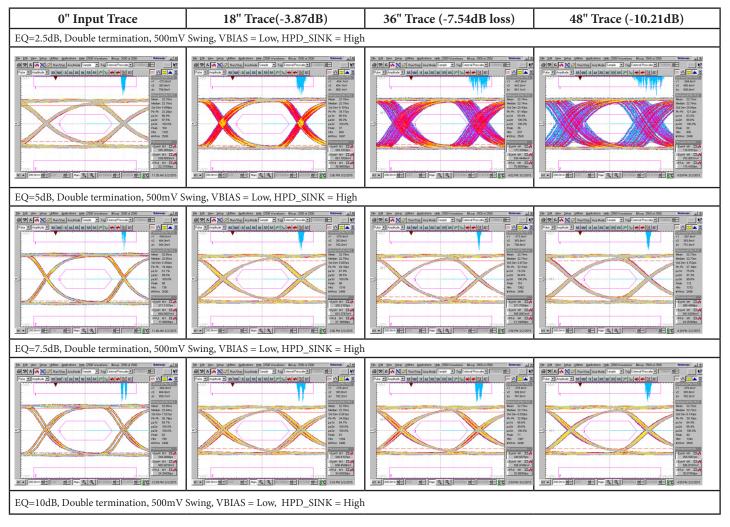
PI3HDX511F

5.4 Output Eye: EQ Settings and Input Trace Length (Informative)

5.4.1 Test Setup

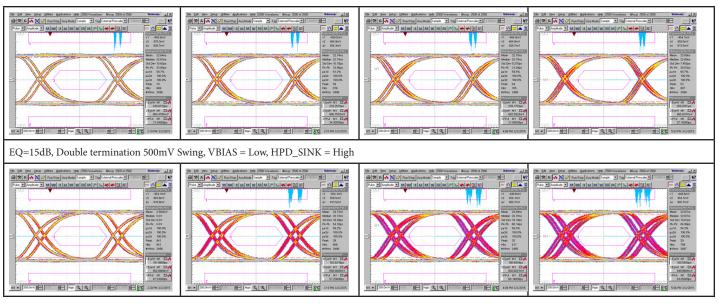


5.4.2 Output waveforms





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Note: For system designers reference, characterization trace board insertion Loss Informations and picture image are shown below.

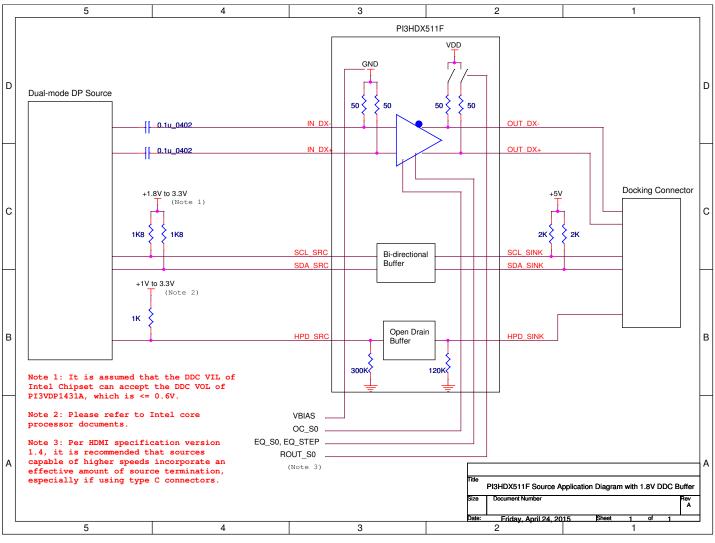
Frequency @3.4Gbps	4-in	6-in	12-in	18-in	24-in	30-in	36-in	48-in	Unit
Insertion Loss	-0.9	-1.34	-2.54	-3.87	-5.17	-6.34	-7.54	-10.21	dB





6. Application

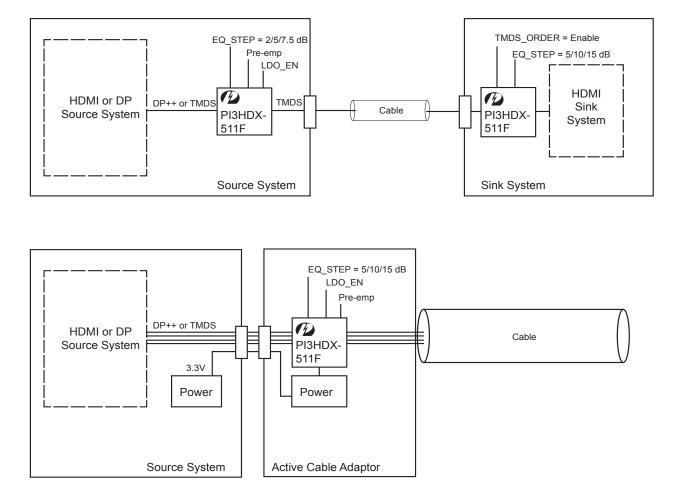
6.1 HDMI 1.8V DDC Buffer Usage Case





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6.2 Application Block Diagram

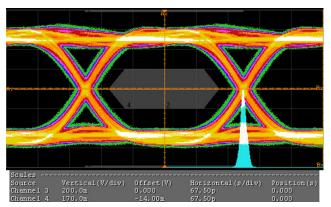




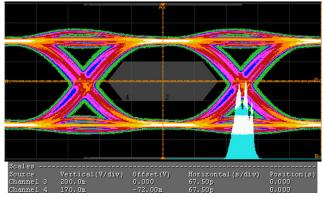


6.3 Output Eye Measurement Data

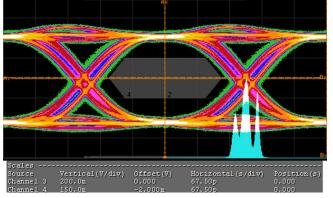
Sink Apps test set-up: Output Eye Diagram with different EQ settings of 1.5dB, 10dB and 15 dB. Trace Cards used with 24", 48" and 84" with 2 meter HDMI Cable with proper pre-emphasis setting.



24" Input (-15.46dB loss) , EQ=2.5dB, 500mV Swing, Preemp =1.5dB, Rout_S0=1



48" Input, EQ=10dB, 500mV Swing, Pre-emp=0dB, Rout_ S0=1



84" Input, EQ=15dB, 500mV Swing, Pre-emp=0dB, Rout_ S0=1

Note: For system designers reference, AE-trace board information are shown below. Insertion loss is measured in the 3GHz (6.0 Gbps) speed.

FR4 trace length	0-in	6-in	12-in	18-in	24-in	30-in	36-in	Units
Insertion loss (dB)	-5.52	-9.35	-10.07	-12.66	-15.46	-16.57	-20.81	dB



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6.4 Layout Guidelines

As transmission data rate increases rapidly, any flaws and/or mis-matches on PCB layout are amplified in terms of signal integrity. Layout guideline for high-speed transmission is highlighted in this application note.

6.4.1 Power and Ground

To provide a clean power supply for Pericom high-speed device, few recommendations are listed below:

- Power (VDD) and ground (GND) pins should be connected to corresponding power planes of the printed circuit board directly without passing through any resistor.
- The thickness of the PCB dielectric layer should be minimized such that the VDD and GND planes create low inductance paths.
- One low-ESR 0.1uF decoupling capacitor should be mounted at each VDD pin or should supply bypassing for at most two VDD pins. Capacitors of smaller body size, i.e. 0402 package, is more preferable as the insertion loss is lower. The capacitor should be placed next to the VDD pin.
- One capacitor with capacitance in the range of 4.7uF to 10uF should be incorporated in the power supply decoupling design as well. It can be either tantalum or an ultra-low ESR ceramic.
- A ferrite bead for isolating the power supply for Pericom high-speed device from the power supplies for other parts on the printed circuit board should be implemented.
- Several thermal ground vias must be required on the thermal pad. 25-mil or less pad size and 14-mil or less finished hole are recommended.

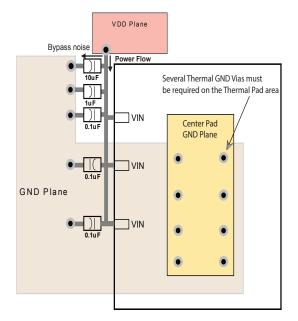


Figure 6-1 Decoupling Capacitor Placement Diagram

6.4.2 High-speed signal Routing

Well-designed layout is essential to prevent signal reflection:

- For 90 Ω differential impedance, width-spacing-width micro-strip of 6-7-6 mils is recommended; for 100 Ω differential impedance, width-spacing-width micro-strip of 5-7-5 mils is recommended.
- Differential impedance tolerance is targeted at ±15%.





Trace and board parameters:	Single-ended mode:
Trace width: $W = 6.0 \textcircled{\bullet} mils$ Trace thickness: $t = 1.9 \textcircled{\bullet} mils (1.39 \text{ oz})$ Trace spacing: $S = 7.0 \textcircled{\bullet} mils$ Dielectric (layer) thickness: $h = 4.4 \textcircled{\bullet} mils (b=10.7 \text{ mils})$ Dielectric (layer) asymmetry: $50 \textcircled{\bullet} \And (h1=4.4, h2=4.4)$ Relative dielectric constant: $\approx 4.11 \textcircled{\bullet}$	$\begin{array}{c c} \mbox{Characteristic} & \mbox{Microstrip} & \mbox{Stripline} \\ \mbox{impedance:} & \mbox{Zo} = & \mbox{50.7} & \mbox{32.9} & \mbox{Ω} \\ \mbox{Capacitance:} & \mbox{Co} = & \mbox{2.70} & \mbox{6.30} & \mbox{pf/in} \\ \mbox{Delay:} & \mbox{Tpd} = & \mbox{137.1} & \mbox{171.6} & \mbox{ps/in} \\ \mbox{Speed:} & \mbox{v} = & \mbox{185.4} & \mbox{148.2} & \mbox{mm/ns} \\ \mbox{Differential mode:} & \mbox{Differential} & \mbox{Microstrip} & \mbox{Stripline} \\ \mbox{Microstrip} & \mbox{Microstrip} & \mbox{Stripline} \\ \mbox{Microstrip} & \mbox{Microstrip} & \mbox{Stripline} \\ \mbox{Microstrip} & Microstri$
PCB edge view $ \begin{array}{c} \downarrow & \longleftarrow & \downarrow^{t} \\ \uparrow & \uparrow_{h} & & \downarrow^{t} \\ \hline & & \downarrow^{h1} & +S^{+} & & \downarrow^{t} \\ \end{array} $	1. Microstrip Zo formula accurate if 0.1 <w h<2)<="" td=""> 2. Stripline Zo formula accurate if (W/b)<0.35</w>
Trace and board parameters: Trace width: $W = 5.0 \Rightarrow$ mils Trace thickness: $t = 1.9 \Rightarrow$ mils (1.39 oz) Trace spacing: $S = 7.0 \Rightarrow$ mils Dielectric (layer) thickness: $h = 4.4 \Rightarrow$ mils (b=10.7 mils) Dielectric (layer) asymmetry: $50 \Rightarrow$ % (h1=4.4, h2=4.4) Relative dielectric constant: $e 4.1 \Rightarrow$	Single-ended mode:MicrostripStriplineCharacteristic impedance: 36.7 $Capacitance:36.7Capacitance:0Capacitance:Delay:Speed:Capacitance:Tpd=137.1171.6148.2mm/ns171.6ps/inDifferential mode:$
PCB edge view $t \leftarrow W \rightarrow +S \rightarrow \qquad $	Microstrip Stripline impedance: Zo= 99.3 69.5 Ω 1. Microstrip Zo formula accurate if 0.1 2. Stripline Zo formula accurate if (W/b) 3. Stripline Zo formula accurate if (b/t)>4

Figure 6-2 Trace Width and Clearance of Micro-strip and Strip-line

For micro-strip, using 1/2oz Cu is fine. For strip-line in 6+ PCB layers, 1oz Cu is more preferable.

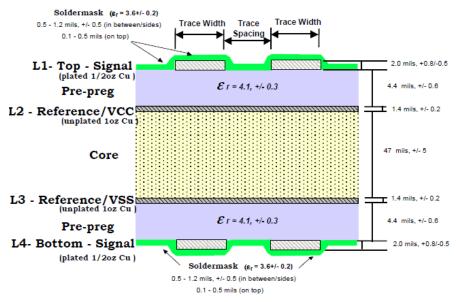


Figure 6-3 4-Layer PCB Stack-up Example



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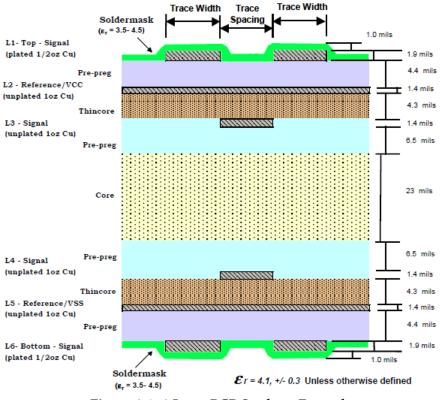


Figure 6-4 6-Layer PCB Stack-up Example

Ground referencing is highly recommended. If unavoidable, stitching capacitors of 0.1uF should be placed when reference plane is changed.

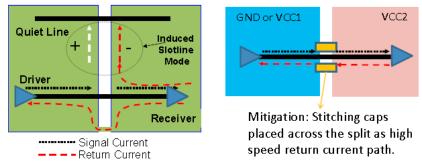


Figure 6-5 Stitching Capacitor Placement

- To keep the reference unchanged, stitching vias must be used when changing layers.
- Differential pair should maintain symmetrical routing whenever possible. The intra-pair skew of micro-strip should be less than 5 mils.
- To keep the reference unchanged, stitching vias must be used when changing layers.
- Differential pair should maintain symmetrical routing whenever possible. The intra-pair skew of micro-strip should be less than 5 mils.



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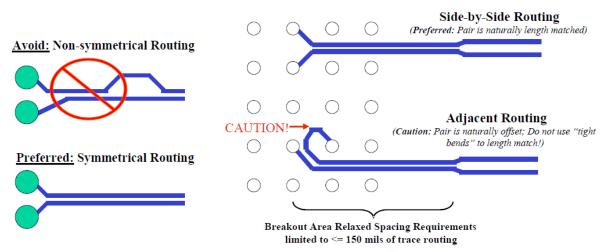


Figure 6-6 Layout Guidance of Matched Differential Pair

- For minimal crosstalk, inter-pair spacing between two differential micro-strip pairs should be at least 20 mils or 4 times the dielectric thickness of the PCB.
- Wider trace width of each differential pair is recommended in order to minimize the loss, especially for long routing. More consistent PCB impedance can be achieved by a PCB vendor if trace is wider.
- Differential signals should be routed away from noise sources and other switching signals on the printed circuit board.
- To minimize signal loss and jitter, tight bend is not recommended. All angles α should be at least 135 degrees. The inner air gap A should be at least 4 times the dielectric thickness of the PCB.

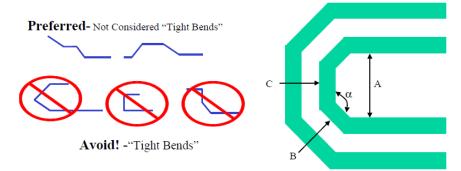


Figure 6-7 Layout Guidance of Bends

• Stub creation should be avoided when placing shunt components on a differential pair.

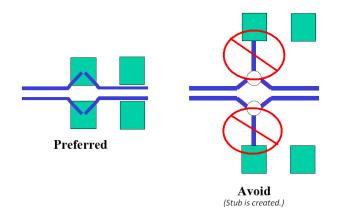






Figure 6-8 Layout Guidance of Shunt Component

• Placement of series components on a differential pair should be symmetrical.

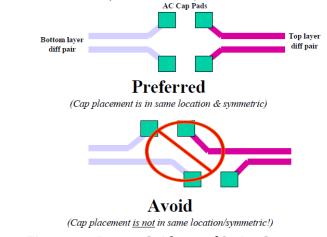
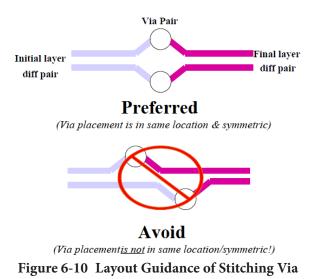


Figure 6-9 Layout Guidance of Series Component

• Stitching vias or test points must be used sparingly and placed symmetrically on a differential pair.





PI3HDX511F

6.5 HDMI Compliance Test

6.5.1 Test Set-up

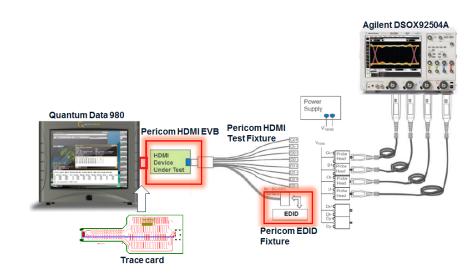


Figure 6-11 HDMI CTS test setup

Note:

(1) Application Trace Card Information

HDMI FR4 trace	0 in	6 in	12 in	18 in	24 in	30 in	36 in	Units
Insertion loss @ 3Gbps (estimated)	-2.96	-4.88	-5.24	-6.53	-7.94	-8.49	-10.60	dB





6.5.2 HDMI Compliance Test Report: Pass

Test Setup : Pericom SMA-to-HDMI Test Fixture, 12" and 36" SMA Cables, Pericom 36" FR4 Trace Cards, 2m 28AWG HDMI Cable.

HDMI Test Report

Overall Result: PASS

Test Configuration Details							
Device Description							
Device ID	Transmitter						
Fixture Type	Other						
Probe Connection	4 Probes						
Probe Head Type	N5444A						
Lane Connection	1 Data Lane						
HDMI Specification	2.0						
HDMI Test Type	TMDS Physical Layer Tests						
	Test Session Details						
Infiniium SW Version	05.20.0013						
Infiniium Model Number	DSOX92504A						
Infiniium Serial Number	MY54410104						
Application SW Version	2.11						
Debug Mode Used	No						
Probe (Channel 1)	Model: N2801A Serial: US54094067 Head: N5444A Atten: Calibrated (18 FEB 2015 11:16:48), Using Cal Atten (5.7831E+000) Skew: Calibrated (18 FEB 2015 11:16:56), Using Cal Skew						
Probe (Channel 2)	Model: N2801A Serial: US54094054 Head: N5444A Atten: Calibrated (18 FEB 2015 11:19:29), Using Cal Atten (5.5882E+000) Skew: Calibrated (18 FEB 2015 11:13:57), Using Cal Skew						
Probe (Channel 3)	Model: N2801A Serial: US54094059 Head: N5444A Atten: Calibrated (18 FEB 2015 11:15:19), Using Cal Atten (5.7320E+000) Skew: Calibrated (18 FEB 2015 11:15:29), Using Cal Skew						
Probe (Channel 4)	Model: N2801A Serial: US54094057 Head: N5444A Atten: Calibrated (18 FEB 2015 11:11:30), Using Cal Atten (5.5123E+000) Skew: Calibrated (18 FEB 2015 11:12:12), Using Cal Skew						
Last Test Date	2016-01-26 13:06:09 UTC +08:00						



PI3HDX511F

Summary of Results

Test Statistics						
Failed 0						
Passed	15					
Total	15					

Margin Thresholds Warning < 2 % Critical < 0 %

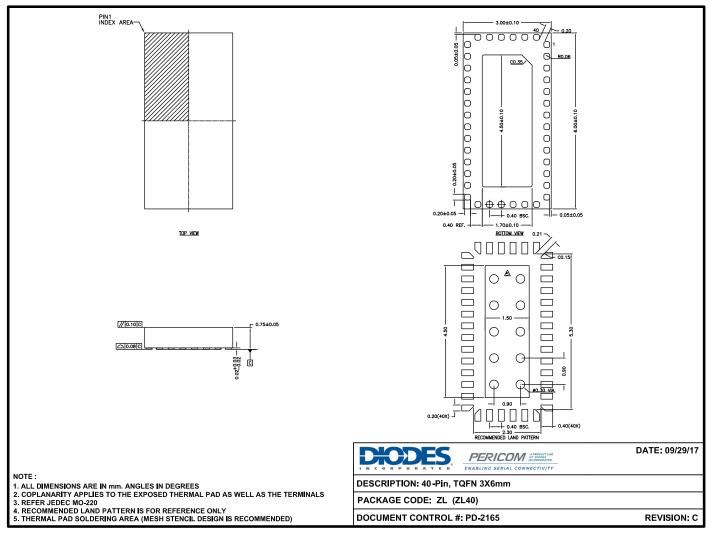
Pass	# Failed	# Trials	Test Name	Actual Value	Margin	Pass Limits
\checkmark	0	1	7-9: Clock Jitter	144 mTbit	42.4 %	VALUE <= 250 mTbit
\checkmark	0	1	7-4: Clock Rise Time	123.410 ps	64.5 %	VALUE >= 75.000 ps
\checkmark	0	1	7-4: Clock Fall Time	122.160 ps	62.9 %	VALUE >= 75.000 ps
√	0	1	7-8: Clock Duty Cycle(Minimum)	49.470	23.7 %	>=40%
\checkmark	0	1	7-8: Clock Duty Cycle(Maximum)	50.130	16.5 %	<=60%
✓	0	1	7-10: D0 Data Jitter	249 m	17.0 %	<=0.3Tbit
\checkmark	0	1	7-4: D0 Rise Time	104.503 ps	39.3 %	VALUE >= 75.000 ps
\checkmark	0	1	7-4: D0 Fall Time	108.363 ps	44.5 %	VALUE >= 75.000 ps
\checkmark	0	1	7-2: VL Clock +	2.853 V	15.7 %	LowerLimit V <= VALUE <= 2.900 V
\checkmark	0	1	7-2: VL Clock -	2.845 V	18.3 %	LowerLimit V <= VALUE <= 2.900 V
√	0	1	7-7: Intra-Pair Skew - Clock	115 mTbit	11.7 %	-150 mTbit <= VALUE <= 150 mTbit
\checkmark	0	1	7-2: VL D0+	2.848 V	17.3 %	LowerLimit V <= VALUE <= 2.900 V
\checkmark	0	1	7-2: VL D0-	2.853 V	15.7 %	LowerLimit V <= VALUE <= 2.900 V
\checkmark	0	1	7-7: Intra-Pair Skew - Data Lane 0	81 mTbit	23.0 %	-150 mTbit <= VALUE <= 150 mTbit
\checkmark	0	1	7-10: D0 Mask Test	0.000	50.0 %	No Mask Failures





7. Mechanical Packaging

7.1 Mechanical Outline





A product Line of Diodes Incorporated PI3HDX511F

7.2 Part Marking Information

Our standard product mark follows our standard part number ordering information, except for those products with a speed letter code. The speed letter code mark is placed after the package code letter, rather than after the device number as it is ordered. After electrical test screening and speed binning has been completed, we then perform an "add mark" operation which places the speed code letter at the end of the complete part number.

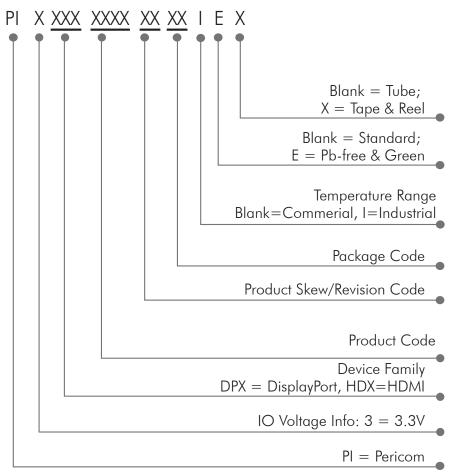


Figure 7-1 Part marketing information





7.3 Tape & Reel Materials and Design

Carrier Tape

The Pocketed Carrier Tape is made of Conductive Polystyrene plus Carbon material (or equivalent). The surface resistivity is 10⁶Ohm/sq. maximum. Pocket tapes are designed so that the component remains in position for automatic handling after cover tape is removed. Each pocket has a hole in the center for automated sensing if the pocket is occupied or not, thus facilitating device removal. Sprocket holes along the edge of the center tape enable direct feeding into automated board assembly equipment. See Figures 3 and 4 for carrier tape dimensions.

Cover Tape

Cover tape is made of Anti-static Transparent Polyester film. The surface resistivity is 10⁷Ohm/Sq. Minimum to 10¹¹Ohm sq. maximum. The cover tape is heat-sealed to the edges of the carrier tape to encase the devices in the pockets. The force to peel back the cover tape from the carrier tape shall be a MEAN value of 20 to 80gm (2N to 0.8N).

Reel

The device loading orientation is in compliance with EIA-481, current version (Figure 2). The loaded carrier tape is wound onto either a 13-inch reel, (Figure 4) or 7-inch reel. The reel is made of Antistatic High-Impact Polystyrene. The surface resistivity 10⁷Ohm/ sq. minimum to 10¹¹Ohm/sq. max.

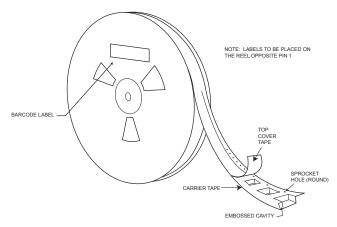


Figure 7-2 Tape & Reel label information

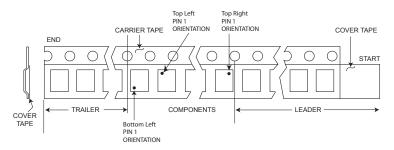


Figure 7-3 Tape leader and trailer pin 1 orientations

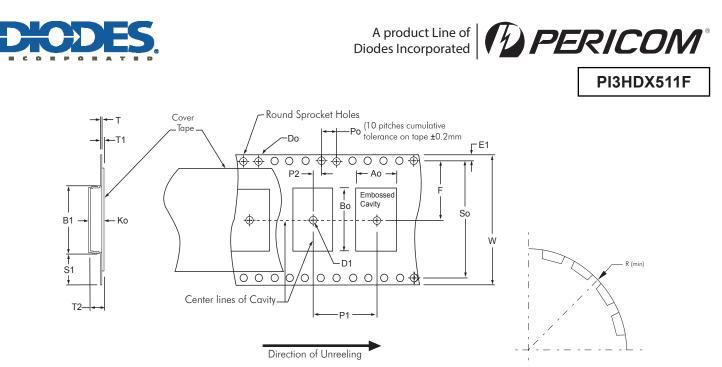


Figure 7-4 Standard embossed carrier tape dimensions

Table 7-1. Constant Dimensions

Tape Size	D0	D1 (Min)	E1	PO	P2	R (See Note 2)	S1 (Min)	T (Max)	T1 (Max)								
8mm		1.0		4.0 ± 0.1	2.0 ± 0.05	25	0.6	0.6	0.1								
12mm		1.5 +0.1 1.5	1.75 ± 0.1			30											
16mm					2.0 ± 0.1												
24mm	-0.0		1.75 ± 0.1	4.0 ± 0.1		2.0 ± 0.1	2.0 ± 0.1	2.0 ± 0.1	2.0 ± 0.1			0.0					
32mm	2.0	50	N/A														
44mm		2.0			2.0 ± 0.15	50	(See Note 3)										

Table 7-2. Variable Dimensions

Tape Size	P ₁	B ₁ (Max)	E ₂ (Min)	F	So	T ₂ (Max.)	W (Max)	A ₀ , B ₀ , & K ₀
8mm	Specific per package type. Refer to FR-0221 (Tape and Reel Packing Information)	4.35	6.25	3.5 ± 0.05	N/A (see note 4)	2.5	8.3	See Note 1
12mm		8.2	10.25	5.5 ± 0.05		6.5	12.3	
16mm		12.1	14.25	7.5 ± 0.1		8.0	16.3	
24mm		20.1	22.25	11.5 ± 0.1		12.0	24.3	
32mm		23.0	N/A	14.2 ± 0.1	28.4± 0.1	12.0	32.3	
44mm		35.0	N/A	20.2 ± 0.15	40.4 ± 0.1	16.0	44.3	

NOTES:

1. A0, B0, and K0 are determined by component size. The cavity must restrict lateral movement of component to 0.5mm maximum for 8mm and 12mm wide tape and to 1.0mm maximum for 16,24,32, and 44mm wide carrier. The maximum component rotation within the cavity must be limited to 200 maximum for 8 and 12 mm carrier tapes and 100 maximum for 16 through 44mm.

2. Tape and components will pass around reel with radius "R" without damage.

3. S1 does not apply to carrier width \geq 32mm because carrier has sprocket holes on both sides of carrier where Do \geq S1.

4. So does not exist for carrier \leq 32mm because carrier does not have sprocket hole on both side of carrier.





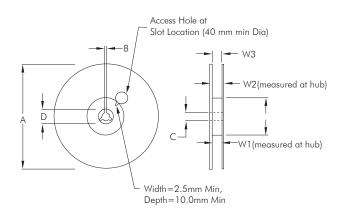


Table 7-3. Reel dimensions by tape size

Tape Size	А	N (Min) See Note A	W1	W2(Max)	W3	B (Min)	С	D (Min)
8mm	170.00		8.4 +1.5/-0.0 mm	14.4 mm	Shall Accom- modate Tape Width Without Interference	1.5mm	13.0 +0.5/- 0.2 mm	20.2mm
12mm	178±2.0mmor 330±2.0mm	60 ±2.0mm or 100±2.0mm	12.4 +2.0/-0.0 mm	18.4 mm				
16mm	330 ±2.0mm	100 ±2.0mm	16.4 +2.0/-0.0 mm	22.4 mm				
24mm			24.4 +2.0/-0.0 mm	30.4 mm				
32mm			32.4 +2.0/-0.0 mm	38.4 mm				
44mm			44.4 +2.0/-0.0 mm	50.4 mm				

NOTE:

A. If reel diameter $A=178 \pm 2.0$ mm, then the corresponding hub diameter (N(min) will by 60 ± 2.0 mm. If reel diameter $A=330\pm 2.0$ mm, then the corresponding hub diameter (N(min)) will by 100 ± 2.0 mm.



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